

STPS3045C-Y

Automotive power Schottky rectifier

Features

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low thermal resistance
- Avalanche rated
- AEC-Q101 qualified

Description

This device is a dual center tap Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in D²PAK, this device is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

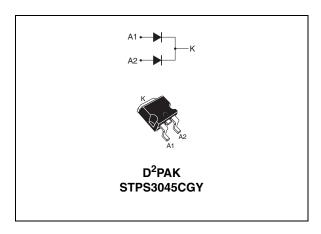


Table 1. Device summary

I _{F(AV)}	2 x 15 A	
V_{RRM}	45 V	
T _{j (max)}	175 °C	
V _{F (max)}	0.57 V	

Characteristics STPS3045C-Y

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			45	V
I _{F(RMS)}	Forward rms voltage			30	Α
I _{F(AV)}	Average forward current δ = 0.5 T_C = 155 °C $Per diode$ Per device		10 30	Α	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			220	Α
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \mu s T_j = 25 ^{\circ}C$			6000	W
T _{stg}	Storage temperature range			-65 to +175	°C
T _j	Maximum operating junction temperature ⁽¹⁾			-40 to +175	°C
dV/dt	Critical rate of rise reverse voltage			10000	V/µs

^{1.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance parameters

Symbol	Parameter		Value	Unit
R _{th (j-c)}	Junction to case	Per diode Total	1.60 0.85	° C/W
R _{th (c)}	Coupling		0.10	° C/W

When the diodes 1 and 2 are used simultaneously:

 ΔT_i (diode 1) = P(diode1) x $R_{th(i-c)}$ (Per diode) + P(diode 2) x $R_{th(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾ Reverse leakage current	Payaraa laakaga aurrant	T _j = 25 °C	V - V	-	-	200	μΑ
	T _j = 125 °C	$V_R = V_{RRM}$	-	11	40	mA	
V _F ⁽¹⁾ Forward voltage drop		T _j = 125 °C	I _F = 15 A	-	0.5	0.57	
	Forward voltage drop	T _j = 25 °C	I _F = 30 A	-	-	0.84	V
		T _j = 125 °C		-	0.65	0.72	

^{1.} Pulse test: $t_p = 380 \mu s$, $\delta < 2\%$

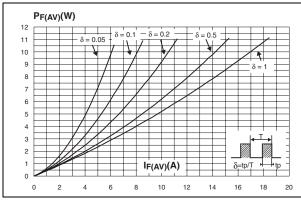
To evaluate the conduction losses use the following equation:

$$P = 0.42 \text{ x } I_{F(AV)} + 0.01 I_{F}^{2}_{(RMS)}$$

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Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)

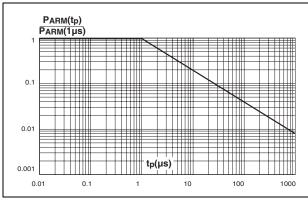
Average forward current versus ambient temperature (δ = 0.5, per diode)



| F(AV)(A)
| 18
| 16
| 14
| 12
| 10
| 8
| 6
| 4
| 2
| 5 | 100 | 125 | 150 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 175 | 17

Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature



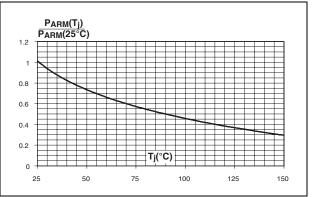
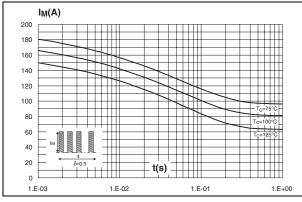
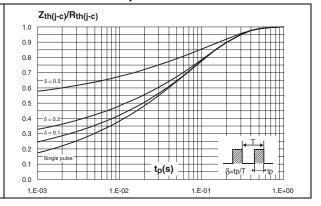


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

Figure 6. Relative variation of thermal impedance junction to ambient versus pulse duration

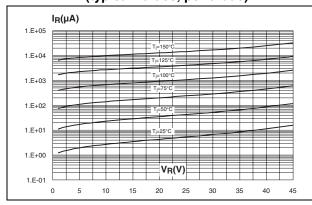




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Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)



C(nF)

10000

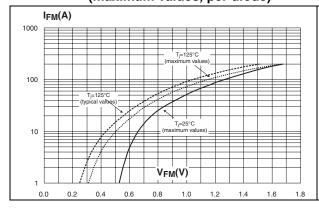
VR(V)

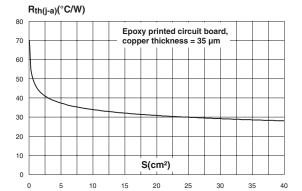
1000

1 10 10 100

Figure 9. Forward voltage drop versus forward current (maximum values, per diode)

Figure 10. Thermal resistance junction to ambient versus copper surface under tab





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2 Package information

- Epoxy meets UL94,V0
- Lead-free package

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Table 5. Package dimensions D²PAK

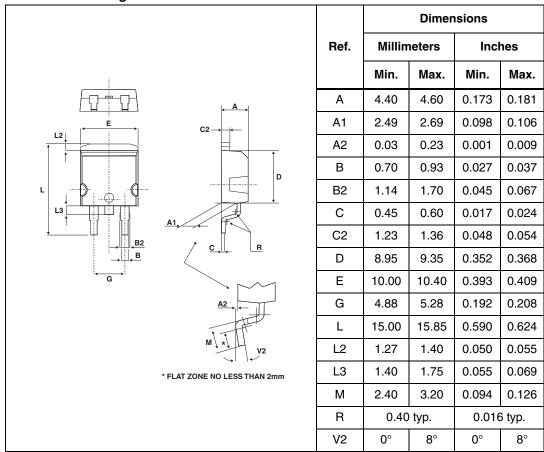
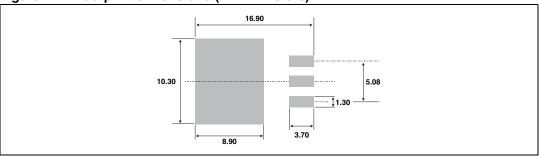


Figure 11. Footprint dimensions (in millimeters)



Ordering information STPS3045C-Y

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS3045CGY-TR	STPS3045CGY	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

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Table 7. Document revision history

Date	Revision	Changes
24-May-2011	1	Initial release.

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